Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-205-9930

Inclosure Material:

Metal

**Overall Length:** 

1.062 inches

Mounting Facility Quantity:

1

### **Mounting Method:**

Threaded stud

**Features Provided:** 

Hermetically sealed case

## **Overall Width Across Flats:**

1.227 inches

Thread Size:

0.500 inches

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

900.0 breakover voltage, dc

**Current Rating Per Characteristic:** 

900.00 amperes forward current, average absolute

# Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector blank

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

## **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

---

#### Demilitarization:

No

Fiig:

A110a0